

NEC's NPN SiGe HIGH FREQUENCY TRANSISTOR

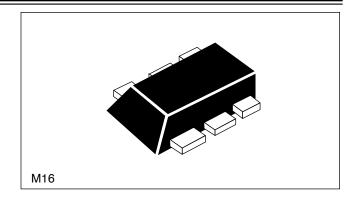
NESG2021M16

FEATURES

- HIGH BREAKDOWN VOLTAGE SiGe TECHNOLOGY VCEO = 5 V (Absolute Maximum)
- LOW NOISE FIGURE:
 NF = 0.9 dB at 2 GHz

NF = 1.3 dB at 5.2 GHz

- HIGH MAXIMUM STABLE GAIN: MSG = 22.5 dB at 2 GHz
- LOW PROFILE M16 PACKAGE: 6-pin lead-less minimold



DESCRIPTION

NEC's NESG2021M16 is fabricated using NEC's high voltage Silicon Germanium process (UHS2-HV), and is designed for a wide range of applications including low noise amplifiers, medium power amplifiers, and oscillators.

ELECTRICAL CHARACTERISTICS (TA = 25°C)

PART NUMBER PACKAGE OUTLINE			NESG2021M16 M16			
	SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	TYP	MAX
RF	NF	Noise Figure at VCE = 2 V, IC = 3 mA, f = 5.2 GHz, Zs = ZSOPT, ZL = ZLOPT	dB		1.3	
	Ga	Associated Gain at VcE = 2 V, Ic = 3 mA, f = 5.2 GHz, Zs = Zsopt, ZL = Zlopt	dB		10.0	
	NF	Noise Figure at VCE = 2 V, IC = 3 mA, f = 2 GHz, Zs = ZSOPT, ZL = ZLOPT	dB		0.9	1.2
	Ga	Associated Gain at VcE = 2 V, Ic = 3 mA, f = 2 GHz, Zs = Zsopt, ZL = Zlopt	dB	15.0	18.0	
	MSG	Maximum Stable Gain ¹ at VcE = 3 V, Ic = 10 mA, f = 2 GHz	dB	20.0	22.5	
	IS21El ²	Insertion Power Gain at VcE = 3 V, Ic = 10 mA, f = 2 GHz	dB	17.0	19.0	
	P _{1dB}	Output Power at 1dB Compression Point at VCE = 3 V, ICQ = 12 mA, f = 2 GHz	dBm		9	
	OIP3	Output 3rd Order Intercept Point at VcE = 3 V, IcQ = 12 mA, f = 2 GHz	dBm		17	
	f⊤	Gain Bandwidth Product at VcE = 3 V, Ic = 10 mA, f = 2 GHz	GHz	20	25	
	Cre	Reverse Transfer Capacitance ² at VcB = 2 V, IE = 0 mA, f = 1 GHz	pF		0.1	0.2
DC	Ісво	Collector Cutoff Current at VcB = 5V, IE = 0	nA			100
	ІЕВО	Emitter Cutoff Current at VEB = 1 V, Ic = 0	nA			100
	hFE	DC Current Gain ³ at VcE = 2 V, Ic = 5 mA		130	190	260

Notes:

1. MSG =
$$\left| \frac{S_{21}}{S_{12}} \right|$$

- 2. Collector to base capacitance when the emitter grounded.
- 3. Pulsed measurement, pulse width \leq 350 μ s, duty cycle \leq 2 %.

ABSOLUTE MAXIMUM RATINGS¹ (TA = 25°C)

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SYMBOLS	PARAMETERS	UNITS	RATINGS			
Vсво	Collector to Base Voltage	٧	13.0			
VCEO	Collector to Emitter Voltage	٧	5.0			
VEBO	Emitter to Base Voltage	V	1.5			
Ic	Collector Current	mA	35			
PT ²	Total Power Dissipation	mW	175			
TJ	Junction Temperature	°C	150			
Тѕтс	Storage Temperature	°C	-65 to +150			

Note:

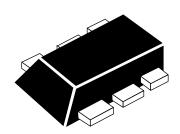
- Operation in excess of any one of these parameters may result in permanent damage.
- 2. Mounted on 1.08 cm² x 1.0 mm (t) glass epoxy PCB.

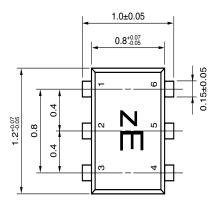
ORDERING INFORMATION

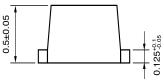
PART NUMBER	QUAN- TITY	SUPPLYING FORM
NESG2021M16-T3-A	10 K pcs reel	Pin 1 (Collector), Pin 6 (Emitter) face the perforation side of the tape

OUTLINE DIMENSIONS (Units in mm)

PACKAGE OUTLINE M16 6-PIN LEAD-LESS MINIMOLD







PIN CONNECTIONS

- 1. Collector 4. Base
- 2. Emitter 5. Emitter
- 2. Emitter 5. Emitter 3. Emitter 6. Emitter

Life Support Applications

These NEC products are not intended for use in life support devices, appliances, or systems where the malfunction of these products can reasonably be expected to result in personal injury. The customers of CEL using or selling these products for use in such applications do so at their own risk and agree to fully indemnify CEL for all damages resulting from such improper use or sale.

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Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices	
Lead (Pb)	< 1000 PPM	-A Not Detected	-AZ (*)
Mercury	< 1000 PPM	Not Detected	
Cadmium	< 100 PPM	Not Detected	
Hexavalent Chromium	< 1000 PPM	Not Detected	
PBB	< 1000 PPM	Not Detected	
PBDE	< 1000 PPM	Not Detected	

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

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